## NSN 5961-00-865-2063

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-865-2063 **Inclosure Material:** Ceramic **Overall Length:** Between 0.800 inches and 0.840 inches **Overall Diameter:** Between 0.292 inches and 0.296 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 80.0 reverse voltage, instantaneous and 60.0 reverse voltage, peak **Current Rating Per Characteristic:** 1.00 amperes source cutoff current preset and 250.00 milliamperes forward current, total rms megahertz **Terminal Type And Quantity:** 1 solder stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: